

2SB0819 (2SB819)

Silicon PNP epitaxial planer type

For low-frequency output amplification
Complementary to 2SD1051

Features

- High collector to emitter voltage V_{CEO} .
- Large collector power dissipation P_C .
- M type package allowing easy automatic and manual insertion as well as stand-alone fixing to the printed circuit board.

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	-50	V
Collector to emitter voltage	V_{CEO}	-40	V
Emitter to base voltage	V_{EBO}	-5	V
Peak collector current	I_{CP}	-3	A
Collector current	I_C	-1.5	A
Collector power dissipation	P_C^*	1	W
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 ~ +150	°C

* Printed circuit board: Copper foil area of 1cm² or more, and the board thickness of 1.7mm for the collector portion

Electrical Characteristics (Ta=25°C)

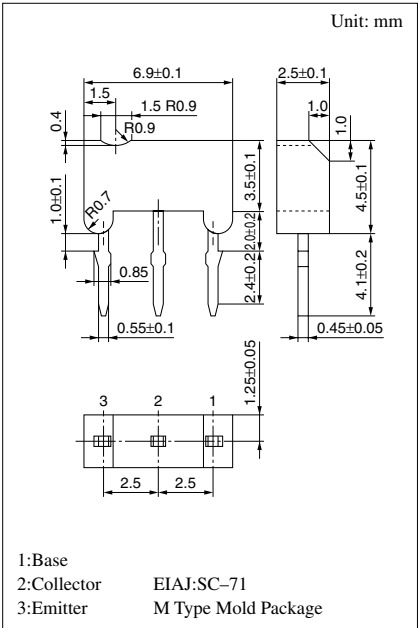
Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = -20V, I_E = 0$			-1	μA
	I_{CEO}	$V_{CE} = -10V, I_B = 0$			-100	μA
Emitter cutoff current	I_{EBO}	$V_{EB} = -5V, I_C = 0$			-10	μA
Collector to base voltage	V_{CBO}	$I_C = -1mA, I_E = 0$	-50			V
Collector to emitter voltage	V_{CEO}	$I_C = -2mA, I_B = 0$	-40			V
Forward current transfer ratio	h_{FE}^{*1}	$V_{CE} = -5V, I_C = -1A^{*2}$	80		220	
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_C = -1.5A, I_B = -0.15A^{*2}$			-1	V
Base to emitter saturation voltage	$V_{BE(sat)}$	$I_C = -2A, I_B = -0.2A^{*2}$			-1.5	V
Transition frequency	f_T	$V_{CB} = -5V, I_E = 0.5A, f = 200MHz$		150		MHz
Collector output capacitance	C_{ob}	$V_{CB} = -20V, I_E = 0, f = 1MHz$		45		pF

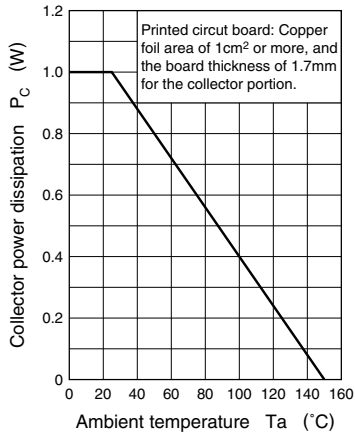
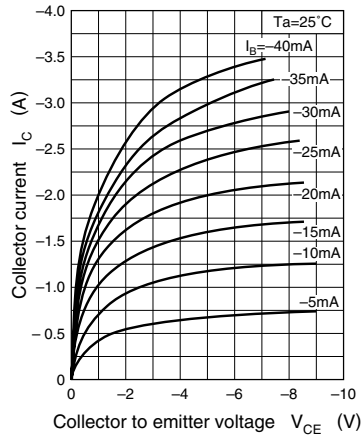
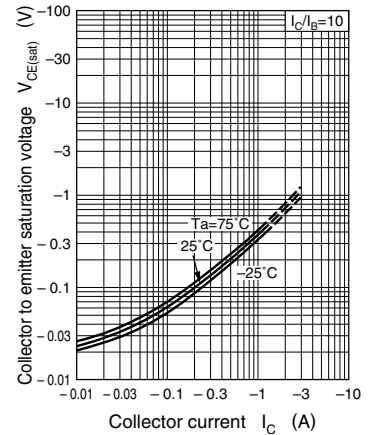
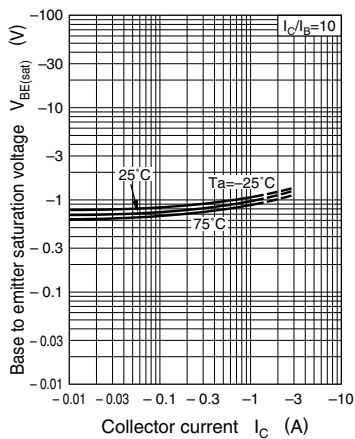
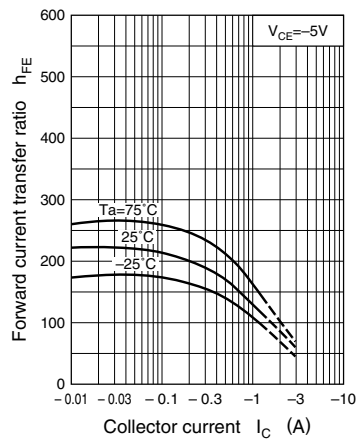
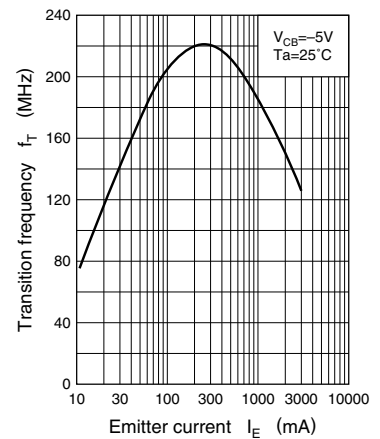
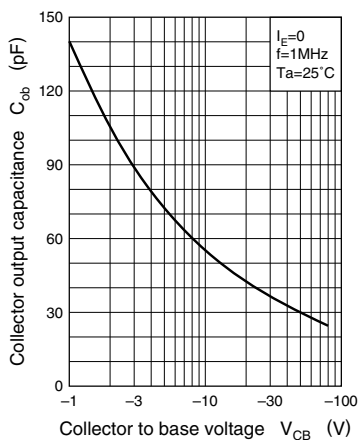
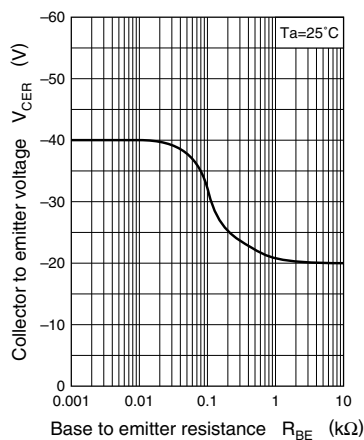
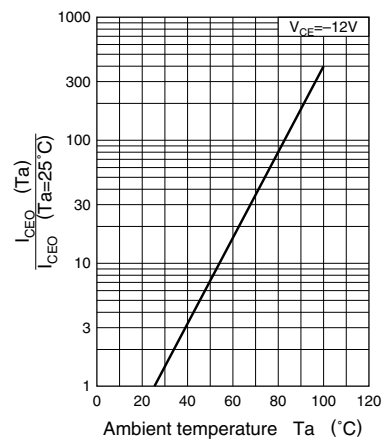
^{*2} Pulse measurement

^{*1} h_{FE} Rank classification

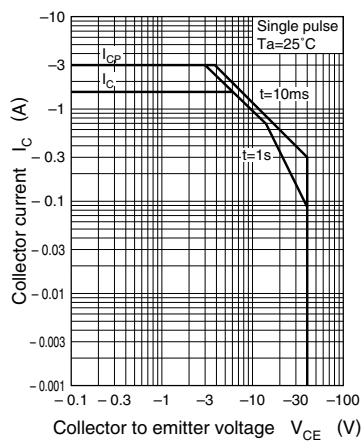
Rank	Q	R
h_{FE}	80 ~ 160	120 ~ 220

Note.) The Part number in the Parenthesis shows conventional part number.



$P_C - T_a$  $I_C - V_{CE}$  $V_{CE(\text{sat})} - I_C$  $V_{BE(\text{sat})} - I_C$  $h_{FE} - I_C$  $f_T - I_E$  $C_{ob} - V_{CB}$  $V_{CER} - R_{BE}$  $I_{CEO} - T_a$ 

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